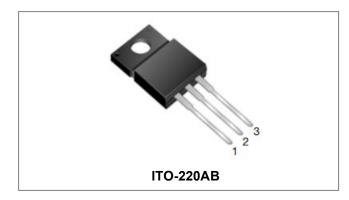


## SDURF1040CTA(CTRA)

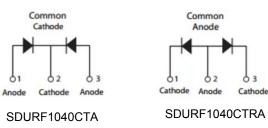
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# SDURF1040CTA(CTRA) ULTRAFAST RECTIFIER



## **Circuit Diagram**



### Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

### Features

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	V <sub>RRM</sub> V <sub>RWM</sub>	-	400	V
DC Blocking Voltage	VR			
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=112°C, rectangular wave form	5(Per Leg) 10(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	80	A

## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V <sub>F1</sub>	@5A, Pulse, TJ = 25°C	0.95	1.40	V
	V <sub>F2</sub>	@5A, Pulse, TJ = 125°C	0.88	1.30	V
Reverse Current(Per Leg)*	I <sub>R1</sub>	$@V_R = rated V_R$ , $T_J = 25^{\circ}C$	0.04	30	μA
	I <sub>R2</sub>	$@V_R = rated V_R$ , $T_J = 125^{\circ}C$	0.015	1	mA
Reverse Recovery Time(Per Leg)	trr	I <sub>F</sub> =500mA, I <sub>R</sub> =1A,and I <sub>m</sub> =250mA	30	35	ns

\* Pulse width < 300 µs, duty cycle < 2%

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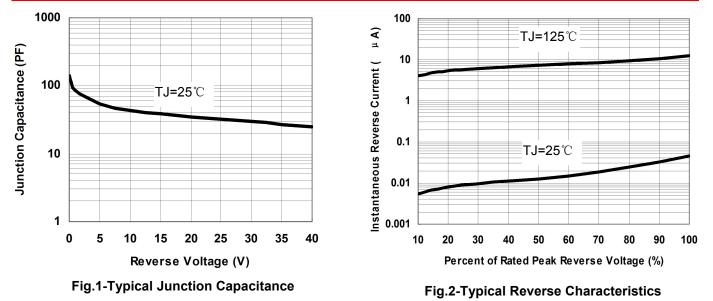
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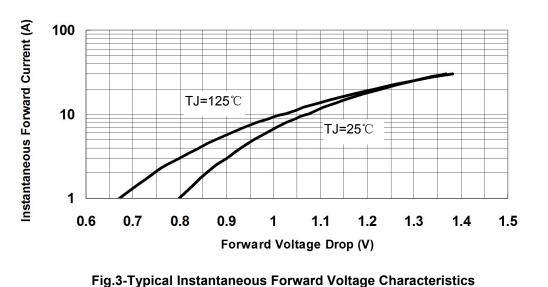
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## Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	3.5	°C/W
Approximate Weight	wt	-	2	g
Case Style		ITO-220AB		

Ratings and Characteristics Curves





China - Germany - Korea - Singapore - United States 
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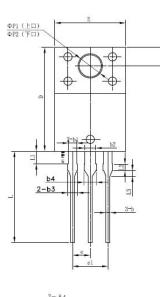


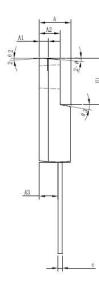
## SDURF1040CTA(CTRA)

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## **Mechanical Dimensions ITO-220AB**





CVMDOI	Millimeters				
SYMBOL	MIN.	TYP.	MAX.		
А	4.30	4.50	4.70		
A1	1.10	1.30	1.50		
A2	2.80	3.00	3.20		
A3	2.50	2.70	2.90		
b	0.50	0.60	0.75		
b1	1.10	1.20	1.35		
b2	1.50	1.60	1.75		
b3	1.20	1.30	1.45		
b4	1.60	1.70	1.85		
с	0.50	0.60	0.75		
D	14.80	15.00	15.20		
E	9.96	10.16	10.36		
e		2.55			
e1		5.10			
H1	6.50	6.70	6.90		
L	12.70	13.20	13.70		
L1	1.60	1.80	2.00		
L2	0.80	1.00	1.20		
L3	0.60	0.80	1.00		
ΦP1(上□)	3.30	3.50	3.70		
<b>ΦΡ2</b> (下口)	2.99	3.19	3.39		
Q	2.50	2.70	2.90		
Θ1		5°			
Θ2		4°			
Θ3		10°			
Θ4		5°			
Θ5		5°			

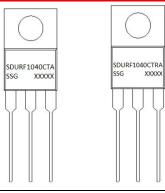
### **Ordering Information**

Device	Package	Shipping
SDURF1040CTA(CTRA)	ITO-220AB (Pb-Free)	50 pcs/ tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

32mm

## **Marking Diagram**



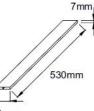
Where XXXXX is YYWWL

SDUR F 10 40 CTA(CTRA SSG YY WW	= Device Type = Package type = Forward Current (10A) = Reverse Voltage (400V) ) = Configuration = SSG = Year = Week = L ot Number
L	= Lot Number
Cautions:	Molding resin Epoxy resin UL:94V-0

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## **Tube Specification**





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